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3 **Toward a Process-Based Molecular Model of SiC Membranes. III.**
4 **Prediction of Transport and Separation of Binary Gaseous Mixtures**
5 **Based on the Atomistic Reactive Force Field**
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22 **ABSTRACT**
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25 The atomistic model of amorphous silicon-carbide membrane that was developed in Parts I
26 and II of this series is utilized in nonequilibrium molecular dynamics (MD) simulations to study
27 transport and separation of equimolar gaseous mixtures H₂/CO₂ and H₂/CH₄ in the membrane
28 at high temperatures. We simulated membranes with up to about 39 nm in thickness, containing
29 up to 170,000 atoms, and up to 100 nanoseconds to obtain reliable statistics. The effect of
30 such parameters as the temperature, the applied pressure drop across the system, and the
31 membrane's thickness on the separation properties was studied. The trends in the dependence
32 of the separation factor on the membrane's thickness are consistent with experiments, namely,
33 the separation factor increases with the thickness up to an optimal value, beyond which it
34 remains constant, or may even decrease. The dependence of the computed separation factor on
35 the membrane's thickness is used in conjunction with the experimental values of the separation
36 factor to estimate the thickness of actual membranes. The results are in agreement with the
37 experimental data, demonstrating the value of MD simulations with a reactive force field for
38 characterizing the properties of complex amorphous films, and flow and transport therein.
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1. Introduction

This paper is the third in a series devoted to the development of a process-based molecular model of silicon-carbide (SiC) nanoporous membranes. By process-based modeling we mean one in which the actual steps in the fabrication of the membranes are mimicked by the molecular simulations. In Part I [1] we described the development of the ReaxFF [2,3] reactive force field directly from quantum mechanics that would permit atomistic studies of the reactive processes involved in the pyrolysis of hydripolycarbosilane (HPCS), $[\text{SiH}_2\text{CH}_2]_n$, the essential step in the fabrication of SiC nanoporous membranes. In Part II [4] we used ReaxFF for reactive molecular dynamics (RMD) simulations of the thermal decomposition of HPCS over a wide range of temperature. Many properties of the material were computed during its pyrolysis, and were found to be in good agreement with the available experimental data. We then simulated pyrolysis of the HPCS under conditions that closely mimic the conditions of the fabrication of nanoporous SiC membranes to produce amorphous SiC material. In particular, we studied the evolution of the gases during the pyrolysis process. All computed properties of the SiC ceramic, as well as those of the evolved gases, were found to be in good agreement with the available experimental data. In particular, the ReaxFF RMD simulations generated ceramic SiC that contains mostly, over 90%, Si-C bonds with some Si-Si and C-C bonds, consistent with experimental data. The agreement demonstrated the accuracy of the parameters of the ReaxFF determined in Part I.

In this paper we use the molecular model of the SiC membranes developed and validated in Parts I and II to study transport and separation of two binary gaseous mixtures, namely, equimolar H_2/CO_2 and H_2/CH_4 , to compare with the SiC membranes that the group at the University of Southern California (USC) has been fabricating [5-9] for such gas separation applications as separation of hydrogen from gaseous mixtures. In addition to its significance for testing the accuracy of the molecular model of SiC nanoporous membranes, the prediction of flow and transport of fluids in porous media are currently of fundamental and practical interest [10], particularly nanoporous materials. First, the energy dissipation caused by friction in confined fluids can cause a rise in the local temperature that, in turn, affects the chemistry of the process. Moreover, in addition to formation of new components and phase transitions, we can expect drastic changes in the fluid's static and dynamic properties that are very different

from those under bulk conditions. Second, it is of clear practical interest to understand the mechanism of transport in the pore space of nanoporous materials, since they are studied intensively for a wide variety of applications. Third, the flow and transport properties provide a probe for characterizing the morphology of the pore space of nanoporous materials.

The SiC membranes that we study contain pores with an average size of a few Å. Due to such exceedingly small pore size, which is comparable with that of the gases under consideration, the main resistance to the flow and transport is controlled by its nano- and micropores. Consequently, the molecular interactions between the gases, and between the gases and the pores' walls are important and must be included. Hence, one must utilize atomistic modeling and simulation to study the transport processes that take place in the membranes' pore space [11].

Thus, in the present paper we use atomistic simulations to study transport and separation of the aforementioned binary mixtures through the SiC membrane model generated in Parts I and II. Here, we apply an external pressure to the membrane to induce separation of the gases in the membrane as they are transported through the membrane, hence requiring nonequilibrium molecular dynamics (NEMD) simulations.

The rest of this paper is organized as follows. Section 2 describes the molecular models, and the procedure for the NEMD calculations. Section 3 presents preliminary results that are utilized to set the parameters of the large-scale MD simulations to be reported in Sec. 4. Then, Sec. 4 describes the approach to steady-state conditions and the implications of the results. The main results, including the effect of the various factors on the separation properties of the membrane, are presented in Section 5, where we also compare the results with the experimental data. The paper is summarized in the last section.

2. Molecular Models and Dual Control Volume-Grand Canonical Molecular Dynamics Simulation

We utilized the dual control volume-grand canonical molecular dynamics (DCV-GCMD) method to study transport and separation of the binary gaseous mixtures in the SiC membranes. This method combines MD and Monte Carlo (MC) simulations [12-14], making it ideal for nonequilibrium systems under such external driving forces as a pressure or chemical potential gradient [15-20]. In this method the system under consideration is partitioned into three regions,

as shown in Figure 1. The origin of the coordinates is taken to be the system’s center. The external driving force is a pressure gradient, applied in the direction of flow and transport (the x direction). The control volumes (CVs) on the left and right sides represent, respectively, the high- and low-pressure regions, which are referred to as h and ℓ CVs. They are in equilibrium with the bulk condition. The middle region represents the amorphous SiC membrane, generated in Parts I and II. Its length (thickness) is nL with n an integer, $n = 1 - 10$. Periodic boundary conditions were employed in the y and z directions. Note that such a model accounts for the pore entrance effects.

The gases and the atoms of the membrane are described by Lennard-Jones (LJ) spheres, characterized by effective LJ size and energy parameters, σ and ε . The standard cut-and-shifted 6-12 LJ potential was used to model the molecule-molecule interactions:

$$U(r) = \begin{cases} U_{LJ}(r) - U_{LJ}(r_c) , & r \leq r_c , \\ 0 , & r > r_c , \end{cases} \quad (1)$$

where, $U_{LJ}(r)$ is the standard 6-12 LJ potential,

$$U_{LJ}(r) = 4\varepsilon \left[\left(\frac{\sigma}{r} \right)^{12} - \left(\frac{\sigma}{r} \right)^6 \right] . \quad (2)$$

r is the distance between the interacting pair, and r_c is the cut-off distance that, after some preliminary simulation, was set to be $9.6 \text{ \AA} \simeq 2.5\sigma_{\text{CH}_4}$. Values of the LJ parameters are listed in Table 1. For unlike pairs of the atoms, the Lorentz-Berthelot mixing rules, $\epsilon_{ij} = (\epsilon_i \epsilon_j)^{1/2}$, and $\sigma_{ij} = \frac{1}{2}(\sigma_i + \sigma_j)$, were used to calculate the size and energy parameters of the pairs. All the quantities of interest were made dimensionless with the help of σ and ε of one of the fluids (denoted by superscript asterisk in the figures). The Verlet velocity algorithm was used to integrate the equations of motion. The Si and C atoms in the membrane itself remained, of course, frozen in their place.

Since the main purpose of using the DCV-GCMD technique is to study the effect of an external pressure gradient on the separation properties of the membrane, the contribution of temperature gradient to the transport is eliminated by holding the temperature constant in the CVs, as well as within the membrane. This was achieved by rescaling the velocity components independently in all the three directions during the entire MD simulation.

The density of each gaseous component in the two CVs must be held at some fixed values in equilibrium with the two bulk phases, and are directly related to the required chemical

potentials and pressures in the corresponding CVs. To obtain constant values of the densities in the two CVs, sufficient number of the grand canonical (GC) MC insertions and deletions of the molecules were carried out in the CVs. The probabilities of inserting and deleting a particle of component i are, respectively, given by

$$p_i^+ = \min \left\{ \frac{Z_i V_c}{N_i + 1} \exp(-\Delta E/k_B T), 1 \right\}, \quad (3)$$

and

$$p_i^- = \min \left\{ \frac{N_i}{Z_i V_c} \exp(-\Delta E/k_B T), 1 \right\}, \quad (4)$$

where ΔE is the potential energy change resulting from inserting or deleting a particle, V_c the volume of the CV, N_i the number of atoms of component i in each CV, k_B the Boltzmann's constant, and Z_i is the absolute activity at temperature T . Values of Z_i are calculated by

$$Z_i = \frac{\exp(\mu_i/k_B T)}{\Lambda_i^3}, \quad (5)$$

where Λ_i and μ_i are, respectively, the de Broglie wavelength and chemical potential of component i . The pressures were converted to equivalent chemical potentials using the Soave equation of state [21], according to which the pressure P is related to the temperature and volume v by

$$P = \frac{RT}{v - b} - \frac{a}{v(v + b)}, \quad (6)$$

where R is the gas constant, and a and b are, respectively, the energy and volume parameters of the equation. The standard mixing rules for a mixture, namely, $a = \sum_i \sum_j y_i y_j a_{ij}$ and $b = \sum_i y_i b_i$, were used, with $a_{ij} = (1 - \delta_{ij})\sqrt{a_i a_j}$, where δ_{ij} is the mixing parameter that we took to be zero. (Other values of δ_{ij} have been reported in the literature, though they are all very small as well.) The Maxwell-Boltzmann distribution was used to assign a thermal velocity to every newly inserted particle in a CV at the given T .

It is crucial in the DCV-GCMD simulations to select an appropriate value for the ratio $\mathcal{R}$, which is the number of GCMC insertions and deletions in each CV relative to the number of the MD steps between successive GCMC steps. This ratio must be chosen such that the correct density and pressure in the CVs are created and maintained during simulations. The optimal value of $\mathcal{R}$ in our simulations was determined to be 10:1. By optimal we mean the smallest value of $\mathcal{R}$ that yields the correct results with computational efficiency. It is important to carry out an enough number of insertions and deletion during GCMC in order to generate and

maintain the appropriate densities in the CVs. A large $\mathcal{R}$ would require, however, expensive long calculations, while a small $\mathcal{R}$ would not generate the right conditions in the two CVs.

During the MD simulations the molecules crossing the outer boundaries of the CVs in x direction were removed. The number of such particles was, however, very small compare to the total number of molecules that were inserted or removed during the GCMC simulations. In addition, for each component and in the membrane region a nonzero streaming velocity - the ratio of the flux to the concentration of each component - was allowed, consistent with the presence of bulk pressure/chemical potential gradients along the flow direction. The absence of nonzero streaming velocity results in severely underestimated fluxes in the transport region. The actual streaming velocities of the molecules in the membrane region were calculated by the MD simulations [15-20].

The DCV-GCMD simulations are computationally expensive. Thus, the computation time was reduced by discretizing the simulation box into $n_x \times n_y \times n_z$ grid points, with the distance between two consecutive grid points equal to 0.43 Å. The interactions between the gases and the Si and C atoms were calculated at each of the grid points, and 3D piecewise cubic Hermite interpolation [22] was used for interpolating the results between the grid points. The results were then saved and used in the simulations. We used a (dimensionless) time step, $\Delta t^* = 10^{-3}$, equivalent to $\Delta t \simeq 1.37 \times 10^{-3}$ ps. The fluxes were calculated at three locations along the membrane - at the entrance to the membrane, and in its middle and at the exit - and were then averaged. The flow and transport process was considered to have reached the steady state when the fluxes computed at various yz planes were within 5% from the averaged value. The equations of motion were integrated over a large number of steps, up to 10^8 steps, within which the steady state was achieved. The number of Si plus C atoms in the simulations varied from about 640 to 1.7×10^5 . Such long simulations with a large number of atoms made it possible to identify a computational strategy that yielded results to be compared with the experimental data. They also made it feasible to study the behavior and flow and transport properties of the membrane under the conditions that are not easily accessible experimentally.

We computed such quantities of interest as the density profiles, the gas fluxes, and the separation factor of the membrane. The density profile $\rho_i^z(x)$ of gas i was computed by dividing the simulation box in the x direction into a resolved grid, and averaging the number of particles of component i over the distance between two neighboring grid points for each MD step. The

density profiles are important to understanding the transport of the gases within the two CVs and the membrane. The flux J_i of each component i was calculated by counting the net number of its particles crossing a given yz plane,

$$J_i = \frac{N_i^{\text{LR}} - N_i^{\text{RL}}}{N\Delta t A_{yz}} , \quad (7)$$

where N_i^{LR} and N_i^{RL} are the number of the particles of type i displacing from the left to the right and vice versa, respectively, A_{yz} is the cross-sectional area, Δt is the MD time step, and N is the number of time steps over which the average was taken, which was every 10^6 steps. The permeability K_i of species i was computed using

$$K_i = \frac{J_i}{\Delta P_i / nL} = \frac{nLJ_i}{\Delta P_i} , \quad (8)$$

where $\Delta P_i = x_i \Delta P$ is the partial pressure drop for species i along the membrane, x_i is the mole fraction of component i ($x_i = 0.5$ in this paper), and ΔP the total pressure drop applied externally to the membrane. The downstream pressure was set to zero in all the cases, which is also the experimental condition. A most important property that is computed for gaseous mixtures and compared with experimental data is the dynamic separation factor S , defined as

$$S = \frac{K_2}{K_1} . \quad (9)$$

3. Preliminary Simulation

The most important contributing factors to the separation properties of a membrane are its thickness, as well as the magnitude of the applied pressure gradient and the temperature at which the separation operation is carried out. Thus, we varied the three factors to study their effect. They included simulations under external pressure drops that varied from 2 atm to 10 atm with increments of 2 atm, and those ranging from 10 atm to 100 atm with increments of 10 atm. In all simulations the pressure drop across the membrane was fixed by setting the upstream pressure in the h -CV equal to the target pressure drop, and the downstream pressure to zero. This provides a better comparison with the experiment in which the gases exit to a large vacuum at zero pressure.

Many simulations were carried out at 25°C, as well as other temperatures, ranging from 100°C to 400°C with increments of 100°C. The membrane's thickness was varied from about

21.4 Å to 128.4 Å, with increments of 21.4 Å, and from 128.4 Å to 1284.2 Å with increments of 128.4 Å. The membrane linear size in the yz plane perpendicular to the direction of the applied pressure gradient was also increased from 21.4 Å with increments of 21.4 Å to 64.2 Å (see below).

As we describe shortly, preliminary simulations indicated that the size of the original molecular model of the SiC membranes generated in Parts I and II was not adequate enough for quantitative simulations. Thus, we increased the size of the original molecular model of the SiC membrane to improve the statistics of the simulations, allow a reasonable number of gas molecules to flow through the system, and to dynamically reach the steady-state condition. Thus, a membrane layer with increasing sizes was constructed by replicating the original model along the three directions until a reasonable size in each direction and for each simulation was achieved. After extensive preliminary simulations, we determined that a reasonable and computationally-affordable cross section of the membrane in the yz planes (perpendicular to the flow and transport in x direction) was of size 64.2×64.2 Å². Then, membranes with various thicknesses along the x direction were constructed using the identified cross section. We emphasize that a goal of the study is to understand how the separation properties of the membrane vary as a function of its thickness.

4. Steady-State Condition

As the first step, one must establish that simulations are carried out correctly in the sense that, the system has reached the steady-state (SS) condition, with constant values of the pressure, temperature, density, and fluxes in the two CVs and, consequently, a constant separation factor. Reaching the SS condition by the GCMD method for the present application proved to be very difficult. Experimentally, the properties are measured for membranes with cross sections and thicknesses of several cm² and μm , respectively, representing a molecularly-large system with billions of atoms. Moreover, the experiments must be carried out for at least several minutes before collecting any data, in order to ensure that the system has reached the SS condition. Therefore, it should be clear that it would be computationally impossible to simulate a system with the size and time scale that are comparable with the experimental conditions, as such simulations are well beyond the capabilities of today's supercomputers. In addition, one more point related to the nature of GCMD simulations requires care. During

GCMD simulations, the MC moves for inserting and deleting gas molecules in the CVs occur every several MD steps, in order to set the required pressures and densities in the two CVs. Since this is done by random insertion and deletion of the gas particles in the two CVs, it causes the fluid flow and transport to experience disturbances after every several time steps, as a result of which the simulations slow down while trying to reach the SS condition.

One solution to this problem is to have sufficiently large CVs and to apply higher external pressures than in the experiment. This provides a sufficiently large number of gas molecules in the CVs that, in turn, provides better statistics after averaging over specified period of times. More importantly, the disturbance caused by the MC moves is minimized. On the other hand, enlarging the system increases the cost of the computations. In addition, to reach the SS condition, the simulations in most cases had to be carried out for more than 100 ns, with the averages taken every one million steps.

Figures 2 and 3 present the dependence of the separation factors on the time for binary mixtures of H_2/CO_2 and H_2/CH_4 , calculated for several pressure drops. As shown, in all the cases, after about 30 million time steps, the separation factors attain constant values, indicating that the SS condition has been reached.

As already pointed out, it is essential to maintain the density of each component in the two CVs at some fixed values, which are in equilibrium with two bulk phases, each at the fixed pressure and gas concentrations corresponding to the individual CVs. The densities, or the corresponding chemical potentials of each component in the CVs, were held constant by carrying out a sufficient number of the GCMC insertions and deletions of the molecules. Figure 4 present the dimensionless density profiles $\rho_i^*(x)$ for the binary mixture H_2/CO_2 at two temperatures and a pressure drop, $\Delta P = 20$ atm, while Figure 5 presents the profiles for two different pressure drops, $\Delta P = 60$ atm and 100 atm, at a same temperature. All the qualitative trends of the density profiles are the same at the two temperatures shown, except that the densities are lower at the higher T , which is expected. In addition, the density profiles are essentially flat in the h (left) CV in the region $-25 < X^* < -8.33$, and are negligible in the (right) downstream ℓ CV in the region $8.33 < X^* < 25$ as the pressure there is zero. Although there are small fluctuations in the densities there, the numerical values of their averages match those obtained with the GCMC method at the same conditions, indicating that the chemical potentials in the two CVs are properly maintained during the DCV-GCMD simulations.

At the entrance to the membrane, $X^* = -8.33$, the density of CO_2 rises sharply due to its affinity for adsorption on the SiC surface. Since the energy parameter for CO_2 -membrane interactions is larger than that of the CH_4 -membrane, more CO_2 molecules accumulate close to the membrane pores' surface than do CH_4 molecules. This is also indicated by the heights of the peaks in the density profiles of the two gases. On the other hand, since the energy parameter for the H_2 -membrane interactions is weak compared with the other interactions, hydrogen has little, if any, affinity for adsorption on the SiC surface, and there is not much H_2 accumulation at the membrane's entrance, explaining why there is no sharp peaks in the H_2 profiles.

In the transport region, $-8.33 < X^* < 8.33$, the density profiles for both components decrease along the X^* direction, which is expected. Due to the existence of the *large* overall bulk pressure gradient (or an overall nonzero streaming velocity) and the heterogeneity of the membrane's structure, however, the density profiles in the membrane are not linear. The total flux is the sum of the diffusive and convective contributions, which result in a nonlinear profile. This is, of course, one plausible explanation, but other ones are also possible. At the same time, the membrane is an amorphous material that is highly heterogeneous with a range of pore sizes and pore connectivities. As a result, the density profiles are not smooth. Similar trends were obtained for the equimolar H_2/CH_4 mixture and, thus, are not shown.

To study the effect of the applied pressure gradient on the transport of a mixture, the temperature of the system must be held constant in order to eliminate any contribution of the temperature gradient to the transport. Hence, special care was taken to achieve this by rescaling the velocity components independently in all the three directions during the entire MD simulation. Figure 6 presents the dimensionless temperatures T^* for the two binary mixtures at two temperatures and for an applied external pressure drop of 20 atm. Each T^* at a (dimensionless) axial position X^* represents an average over the cross section of the membrane at the same X^* . The temperature in the two CVs is completely constant, while small fluctuations exist in the membrane layer (in the middle) that are due to the heterogeneity of the pore space. Figure 7 presents the effect of the external pressure drop on the density profiles for the mixtures H_2/CH_4 .

Let us point out that, as described in Parts I and II, the entire process-based modeling of the fabrication of the membrane was based on MD simulation, which is a completely deterministic process. As such, there is no stochastic element in the system that would require generation

of multiple realizations of the model membrane. In other words, once the force field, the molecular model of the polymer precursor, and the system size are specified, the MD simulation always produces *the same* membrane structure. The only stochastic element in the simulation is the original structure of the polymer. As described in Part II, we initially generated a molecular model of the polymer and then used MD simulation and energy minimization in order to arrive at the equilibrium structure of the polymer. To further check that the true global minimum energy of the polymer had been reached, we also used simulated annealing [23], which is a powerful computational algorithm for determining the global minimum energy state of a disordered system. Of course, similar to any other computer simulations, there are always numerical round-off errors. In addition, one must set a criterion for the system to achieve its global minimum energy state such as, for example, setting the relative change in the total energy of the system to be smaller than a small number ϵ , e.g. 10^{-3} over a number of time steps. But, once ϵ , the force field used in the MD simulation and the temperature of the system are specified, then, regardless of the initial structure of the polymer, its global minimum energy state is *the same*, because the true global minimum energy of the material is unique. In fact, as reported in Part I, and will be reported in a separate paper [24] in the near future, the calculated physical properties of the SiC material that we have generated, ranging from its density, to x-ray diffraction pattern, and radial distribution function, are all in excellent agreement with experimental data, hence indicating that the correct molecular structure of the material has been generated by our MD computations.

5. Effect of Various Factors on Membrane Properties

We next present the effect of various factors on the properties of the membranes. Two of the most important properties are the separation factors and the gases' fluxes.

5.1 Temperature

The permeability K of a species is typically represented as the product of the diffusivity D and solubility S , $K = DS$. Increasing T at a fixed pressure drop ΔP causes the molecules to diffuse much faster, resulting in higher diffusivities. At high temperatures, there is also little, if any, possibility of adsorption of the gases on the pores' surface and, thus, the solubility decreases. Indeed, all of the density profiles presented in Figs. 5 and 6 verify that the amount

of gas adsorbed in the membrane decreases with increasing T . Depending on whether the rate of increase of D with T is larger or smaller than the rate of the decreases in S , the overall fluxes may increase or decrease with T . Figure 8 presents the change in the fluxes of the gases with increasing temperature in the two binary mixtures, when an external pressure drop of $\Delta P = 20$ has been applied to the membrane. As Fig. 8 indicates, in the present case the increase in D is smaller than the decrease in S , so that the overall permeation rates (fluxes) decrease with T . Note, however, that since the membrane is subject to a large pressure gradient, D is an effective diffusivity that represents the combined effect of pure diffusion and the convective effect.

Examination of the MD simulations, and in particular the pressure build-up in the two CVs, indicates that much fewer number of molecules are required at higher temperatures to build up the same pressure and, thus, the net fluxes are smaller. Note that fewer number of molecules implies a less “crowded” space, and thus higher D . It also implies smaller solubility.

Hydrogen is the lightest gas in the two binary mixtures and, therefore, we expect higher temperatures to result in higher separation factors for H_2 over both CO_2 and CH_4 . Figure 8 presents the results of the MD computations, which confirm the trends and indicate that the separation factor is always an increasing function of temperature.

5.2 External pressure drop

Figure 10 presents the dependence on the external pressure drop ΔP of the separation factor for a membrane with the thicknesses $\ell = 64.2 \text{ \AA}$ for the two mixtures that we studied. For a membrane with a given thickness, the separation factor is not sensitive to the applied pressure drop, which justifies imposing in the simulations ΔP s that are larger than those used in the experiments.

5.3 Membrane’s thickness

The separation factor of a membrane depends on its thickness ℓ , but there is an *optimal thickness* ℓ_o such that, a thickness $\ell < \ell_o$ yields a separation factor smaller than the maximum separation that the membrane can attain, whereas the separation factor will not improve and may even decline again, if the membrane is thicker than its optimal thickness. Thus, we studied the dependence of the separation factor on the membrane’s thickness by increasing it from $64.2 \text{ \AA}$ to $385.2 \text{ \AA}$, the largest thickness for which the SS condition could be reached using

an affordable computation time. Figure 11 presents the results for the two binary mixtures when the applied pressure drop was $\Delta P = 20$ atm, while Figures 12 and 13 show the same for $\Delta P = 30$ and 40 atm, respectively. Similar results were obtained for $\Delta P = 50$ and 60 atm and are not shown. In all the cases, the separation factor increases with increasing the membrane's thickness. We then fitted the results to an exponential function,

$$S(\ell) = S_{\infty} + A \exp(-\ell/B) \quad (10)$$

where A and B are constants to be determined, and S_{∞} is the asymptotic separation factor, if we could increase the membrane's thickness to its experimental value. The fitting was carried out for each ΔP . We find that values of A are largely insensitive to the applied pressure drop.

The functional form of Eq. (9) deserves some discussions. Although Eq. (9) is, at this point, purely empirical and intended only for obtaining estimates of the separation factor as a function of the membrane's thickness (see the next section), it is not, in fact, without merit. As described earlier, since the model membrane is exposed to a large pressure gradient, convection plays an important role in the permeation process. If we solve the convection-diffusion equation for a porous medium of finite length ℓ , we find that the concentration profile, and hence the effective diffusivity and the permeability, depend exponentially on the porous medium's length (see Eq. (11.76) of Ref. [10]). As a result, the separation factor, which is simply the ratio of the permeabilities, also depends exponentially on the porous medium length, or the membrane's thickness.

5.4 Comparison with the experimental data

As pointed out earlier, it is currently not feasible to carry out MD simulation of transport and separation of gaseous mixtures in an atomistic model of the SiC membranes with a thickness comparable with that of one that the USC group has been fabricating, which is in the range [7,8] $2 \mu\text{m} - 6 \mu\text{m}$. The experimental separation factors are [7,8] 93 and 104 for the H_2/CO_2 H_2/CH_4 mixtures, respectively, measured at $T = 475$ K. If the trends indicated by Eq. (7) are correct, then, setting S_{∞} to its experimental value should yield a membrane thickness comparable with that of the fabricated membranes. In Table 2 we list the estimated membrane's thickness, using the experimental S_{∞} , for the two mixtures for three external pressure drops ΔP . The estimated thicknesses fall very nicely within the range of experimental thickness of

the membranes. Ultimately, of course, one must increase the thickness of the atomistic model of the membrane to much higher values, in order to obtain more accurate estimates of the parameters A and B , and possibly S_∞ . But, the model developed in Parts I and II and utilized here for the simulation of transport and separation of the two binary gaseous mixtures provide all the correct experimental trends, as well as an accurate estimate the optimal thickness of the membrane, which are very encouraging.

6. Summary

We utilized the atomistic model of amorphous silicon-carbide membrane, developed in Parts I and II of this series, to study transport and separation of equimolar H_2/CO_2 and H_2/CH_4 gaseous mixtures at high temperatures. The dual control volume-grand canonical molecular dynamics simulation was used in order to simulate the transport and separation processes. Membranes of up to 38 nm in thickness were simulated, and the effect of the various parameters on their separation properties is investigated. They include the temperature, the applied pressure drop across the system, and the membrane thickness. The separation factors are insensitive to the pressure drop applied across the membrane, while they are strong functions of the temperature and the membrane's thickness. The trends in the dependence of the separation factor on the membrane's thickness are consistent with what is obtained in experiments. If the dependence of the computed separation factors on the membranes thickness and the experimental values of the separation factors are used as input, the simulations provide estimates of the thickness of the membranes that are in agreement with the experimental data, hence providing more evidence of the accuracy of the atomistic model.

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Table 1: The Lennard-Jones parameters for the various gases and membrane atoms, used in the DCV-GCMD simulations.

Gases and atoms	σ (Å)	ϵ/k_B (K)	Mass
C	3.400	28.0	12.00
Si	3.742	23.6	28.09
H ₂	2.827	59.7	2.04
CO ₂	3.794	225.3	44.01
CH ₄	3.810	148.1	16.04

Table 2: Predicted values of the membrane thickness for the H₂/CO₂ and H₂/CH₄ mixtures for the pressure drops $\Delta P = 20$ and 60 atm. The temperature is 200°C.

mixture	ΔP (atm)	optimal thickness (μm)
H ₂ /CO ₂	20	1.79
H ₂ /CO ₂	60	3.83
H ₂ /CH ₄	20	4.03
H ₂ /CH ₄	60	6.64

Captions

Figure 1. Schematic illustration of the simulation system with the SiC membrane in the middle. The h and l areas represent, respectively, the high- and low-pressure control volumes.

Figure 2. Time-dependance of the separation factor of the membrane for the H₂/CO₂ mixture, exposed to the various pressures drops.

Figure 3. Same as in Figure 2, but for the H₂/CH₄ mixture.

Figure 4. The dimensionless density profiles of the H₂/CO₂ mixture in the axial (X^*) direction in the membrane (middle region) and the two control volumes. The profiles represent averages over the cross section of the membrane.

Figure 5. Same as in Figure 4, but for higher pressure drops.

Figure 6. The average dimensionless temperature T^* in the membrane (middle) and the two control volumes. Numbers in the parentheses indicate the set temperatures. The applied external pressure drop is 20 atm.

Figure 7. The dimensionless density profiles of the H_2/CH_4 mixture in the axial (X) direction. The profiles represent averages over the cross section of the membrane.

Figure 8. Temperature-dependence of the separation factor for the two gaseous mixtures.

Figure 9. Temperature-dependence of the fluxes of the two gaseous mixtures.

Figure 10. Effect of the applied external pressure drop on the separation factor for a membrane of thickness $64.2 \text{ \AA}$.

Figure 11. Effect of the membrane's thickness ℓ on its separation factor for the two gaseous mixtures. The lines represent the fit of the data to Eq. (9), with $A \simeq 91.72$ and $B \simeq 0.39$ for the H_2/CO_2 mixture, and $A \simeq 101.93$ and $B \simeq 0.84$ for the H_2/CH_4 mixture, both at $T = 475 \text{ K}$.

Figure 12. Same as in Figure 11, but for an external pressure drop of 30 atm . The fitting parameters are $A \simeq 91.95$ and $B \simeq 0.42$ for the H_2/CO_2 mixture, and $A \simeq 101.74$ and $B \simeq 1.06$ for the H_2/CH_4 mixture.

Figure 13. Same as in Figure 11, but for an external pressure drop of 40 atm . The fitting parameters are $A \simeq 91.86$ and $B \simeq 0.53$ for the H_2/CO_2 mixture, and $A \simeq 101.44$ and $B \simeq 2.11$ for the H_2/CH_4 mixture.

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GCMD Simulation